



SFAF501G - SFAF508G

Isolated 5.0 AMPS.

Glass Passivated Super Fast Rectifiers

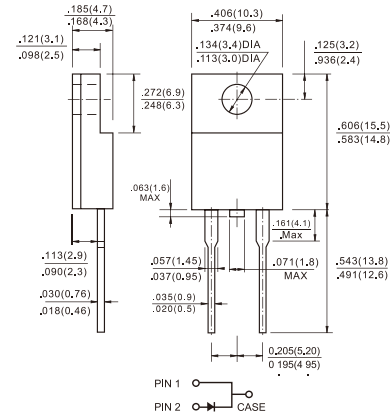
ITO-220AC

Features

- ✧ UL Recognized File # E-326243
- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss.
- ✧ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode.

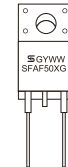
Mechanical Data

- ✧ Case: ITO-220AC molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ High temperature soldering guaranteed: 260°C/10 seconds .16" (4.06mm) from case.
- ✧ Weight: 1.70 grams



Dimensions in inches and (millimeters)

Marking Diagram



SFAF50XG = Specific Device Code
G = Green Compound
Y = Year
WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SFAF 501G	SFAF 502G	SFAF 503G	SFAF 504G	SFAF 505G	SFAF 506G	SFAF 507G	SFAF 508G	Units
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	VRMS	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	VDC	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @T _C = 100 °C	IF(AV)	5.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	IFSM	125								A
Maximum Instantaneous Forward Voltage @ 5.0A	VF	0.975				1.3		1.7		V
Maximum DC Reverse Current at @ T _A =25°C	IR	10								uA
Rated DC Blocking Voltage (Note 1) @T _A =125 °C		400								uA
Maximum Reverse Recovery Time (Note 4)	Trr	35								nS
Typical Junction Capacitance (Note 2)	Cj	70								pF
Typical Thermal Resistance (Note 3)	RθJC	5.0								°C/W
Operating Temperature Range	T _J	-65 to +150								°C
Storage Temperature Range	T _{STG}	-65 to +150								°C

Notes: 1. Pulse Test with PW=300 usec, 1% Duty Cycle
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
3. Mounted on Heatsink Size of 2" x 3" x 0.25" al-Plate.
4. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

RATINGS AND CHARACTERISTIC CURVES (SFAF501G THRU SFAF508G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

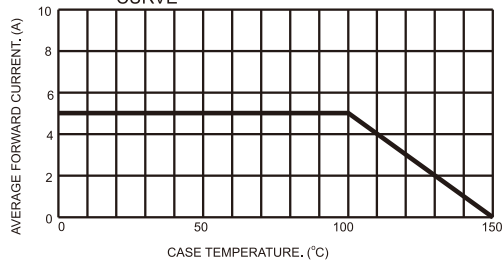


FIG.2- TYPICAL REVERSE CHARACTERISTICS

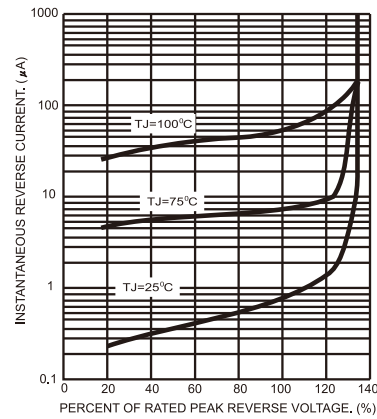


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

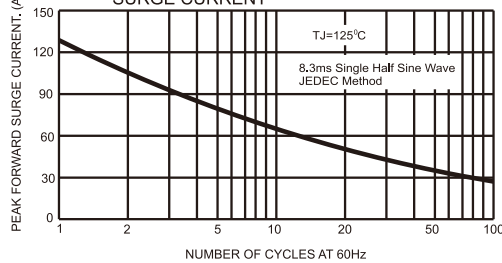


FIG.5- TYPICAL FORWARD CHARACTERISTICS

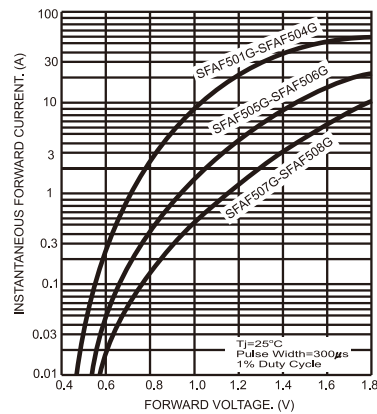


FIG.4- TYPICAL JUNCTION CAPACITANCE

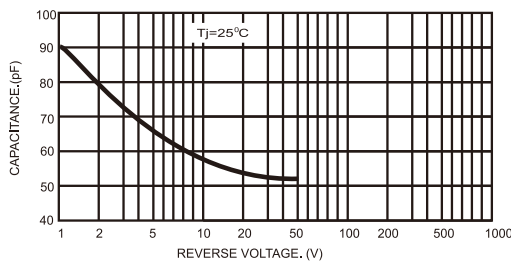


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

